## **CLAIMS**

## What is claimed is:

- A semiconductor device, comprising:
   a first functional die including at least a first pad;
   at least a second functional die including at least a second pad and formed on a common semiconductor substrate with the first functional die; and
   an adjacent die interconnection circuit operably coupling the first pad of the first functional die with the second pad of the at least a second functional die.
- 2. The semiconductor device, as recited in claim 1, wherein the adjacent die interconnection circuit includes at least one conductor segment having a first end electrically coupled to the at least a first pad and a second end electrically coupled to the at least a second pad.
- 3. The semiconductor device, as recited in claim 2, wherein the adjacent die interconnection circuit further includes a conductive bump electrically coupled to the conductor segment configured for operatively coupling the conductor segment of the semiconductor device with a substrate contact of a higher level packaging element.
- 4. The semiconductor device, as recited in claim 1, wherein the first functional die and the at least a second functional die are immediately adjacent.
- 5. The semiconductor device, as recited in claim 1, wherein the first functional die and the at least a second functional die are separated by at least one nonfunctional die.
- 6. The semiconductor device, as recited in claim 2, further comprising: at least one nonfunctional die including at least one pad, the nonfunctional die being formed on the common semiconductor substrate and located thereon between the first functional die and the at least a second functional die; and

wherein the at least one conductor segment extends between the at least a first pad and the at least one pad of the at least one nonfunctional die, the adjacent die interconnection circuit further including a second conductive segment extending between the at least one pad of the at least one nonfunctional die and the at least a second pad.

- 7. The semiconductor device, as recited in claim 6, further comprising a nonfunctional die pad isolation conductive segment including a first end electrically attached to the at least one conductor segment and the second conductive segment for coupling the at least a first pad of the first functional die with the at least a second pad of the at least a second functional die, the nonfunctional die pad isolation conductive segment further including a second end extending to the at least one nonfunctional die pad, the nonfunctional die pad isolation conductive segment being fabricated as an open circuit.
- 8. The semiconductor device, as recited in claim 6, wherein the at least one nonfunctional die further includes an isolation device coupled to the at least one pad of the at least one nonfunctional die for electrically isolating the at least one nonfunctional die from the adjacent die interconnection circuit.
- 9. A segment of a semiconductor wafer, comprising: two or more functional dice each including at least one pad, the two or more functional dice being on a unitary semiconductor wafer segment; and an adjacent die interconnection circuit for mutually operably coupling each at least one pad of the two or more functional dice to at least one other pad of the two or more functional dice.
- 10. The segment of a semiconductor wafer, as recited in claim 9, wherein the adjacent die interconnection circuit couples the two or more functional dice identified by testing of the semiconductor wafer to determine an operational status of each die on the semiconductor wafer.
- 11. The segment of semiconductor wafer, as recited in claim 9, wherein the adjacent die interconnection circuit includes a conductor segment for coupling between each of the two or more

functional dice, the conductor segment including a first end electrically coupled to the at least one pad on one of the two or more functional dice and a second end electrically coupled to the at least one pad on another of the two or more functional dice.

- 12. The segment of semiconductor wafer, as recited in claim 9, further comprising: at least one nonfunctional die including at least one pad, the nonfunctional die being formed on the common semiconductor substrate and located thereon with the two or more functional dice; and
- wherein the adjacent die interconnection circuit extends between the at least one pad to the at least one pad of the two or more functional dice.
- 13. The segment of semiconductor wafer, as recited in claim 9, wherein the two or more functional dice are immediately adjacent on the segment of semiconductor wafer.
- 14. The segment of semiconductor wafer, as recited in claim 9, wherein the two or more functional dice are separated by at least one nonfunctional die on the segment of semiconductor wafer.
  - 15. A semiconductor wafer, comprising:
- a plurality of dice each including a pad, the plurality of dice segregated according to functional dice and nonfunctional dice; and
- an adjacent die interconnection circuit operably coupling a first pad of a first functional die with a second pad of a second functional die, the first functional die and the second functional die being operatively adjacent.
- 16. The semiconductor wafer, as recited in claim 11, wherein the first functional die and the second functional die are immediately adjacent on the semiconductor wafer.

- 17. The semiconductor wafer, as recited in claim 11, wherein the first functional die and the second functional die are separated by at least one nonfunctional die on the semiconductor wafer.
- 18. The semiconductor wafer, as recited in claim 15, wherein the adjacent die interconnection circuit includes at least one conductor segment having a first end electrically coupled to the at least a first pad and a second end electrically coupled to the at least a second pad for electrically coupling the at least a first pad with the at least a second pad.
- 19. The semiconductor wafer, as recited in claim 18, wherein the adjacent die interconnection circuit further includes a conductive bump electrically coupled to the conductor segment configured for operatively coupling the conductor segment of the semiconductor device with a contact of higher level packaging.
- 20. The semiconductor wafer, as recited in claim 18, further comprising: at least one nonfunctional die including at least one pad, the nonfunctional die being formed on the common semiconductor substrate and located thereon between the first functional die and the at least a second functional die; and
- wherein the at least one conductor segment extends between the at least a first pad and the at least one pad of the at least one nonfunctional die, the adjacent die interconnection circuit further including a second conductive segment extending between the at least one pad of the at least one nonfunctional die and the at least a second pad.
- 21. The semiconductor wafer, as recited in claim 20, further comprising a nonfunctional die pad isolation conductive segment including a first end electrically attached to the at the at least one conductor segment and the second conductive segment for coupling the at least a first pad of the first functional die with the at least a second pad of the at least a second functional die, the nonfunctional die pad isolation conductive segment further including a second end extending to the at least one nonfunctional die pad, the nonfunctional die pad isolation conductive segment being fabricated as an open circuit.

- 22. The semiconductor wafer, as recited in claim 20, wherein the at least one nonfunctional die further includes an isolation device coupled to the at least one pad of the at least one nonfunctional die for electrically isolating the at least one nonfunctional die from the adjacent die interconnection circuit.
- 23. A memory module, comprising: a substrate including contacts extending to electrical connections to higher-level packaging; and a semiconductor device, including:

a first functional die including at least a first pad;
at least a second functional die including at least a second pad; and
an adjacent die interconnection circuit operably coupling the first pad of the first
functional die with the second pad of the at least a second functional die, the
first functional die and the second functional die being jointly fabricated on a
single semiconductor substrate, the adjacent die interconnect extending
electrical connection to the contacts of the substrate.

- 24. The memory module, as recited in claim 23, wherein the adjacent die interconnection circuit includes at least one conductor segment having a first end electrically coupled to the at least a first pad and a second end electrically coupled to the at least a second pad.
- 25. The memory module, as recited in claim 24, wherein the adjacent die interconnection circuit further includes a conductive bump electrically coupled to the conductor segment configured for operatively coupling the conductor segment of the semiconductor device with the substrate contact.
- 26. The memory module, as recited in claim 23, wherein the first functional die and the at least a second functional die are immediately adjacent on the semiconductor device.

- 27. The memory module, as recited in claim 23, wherein the first functional die and the at least a second functional die are separated by at least one nonfunctional die on the semiconductor device.
- 28. The memory module, as recited in claim 24, further comprising: at least one nonfunctional die including at least one pad, the nonfunctional die being formed on the common semiconductor substrate and located thereon between the first functional die and

the at least a second functional die; and

- wherein the at least one conductor segment extends between the at least a first pad and the at least one pad of the at least one nonfunctional die, the adjacent die interconnection circuit further including a second conductive segment extending between the at least one pad of the at least one nonfunctional die and the at least a second pad.
- 29. The memory module, as recited in claim 28, further comprising a nonfunctional die pad isolation conductive segment including a first end electrically attached to the at the at least one conductor segment and the second conductive segment for coupling the at least a first pad of the first functional die with the at least a second pad of the at least a second functional die, the nonfunctional die pad isolation conductive segment further including a second end extending to the at least one nonfunctional die pad, the nonfunctional die pad isolation conductive segment being fabricated as an open circuit.
- 30. The memory module, as recited in claim 28, wherein the at least one nonfunctional die further includes an isolation device coupled to the at least one pad of the at least one nonfunctional die for electrically isolating the at least one nonfunctional die from the adjacent die interconnection circuit.
- 31. An electronic system, comprising:
  at least one processor device; and
  at least one memory module for operably coupling with the at least one processor device, the at least
  one memory module including:

a substrate including contacts extending to electrical connections to higher-level packaging; and

a semiconductor device, including:

a first functional die including at least a first pad;
at least a second functional die including at least a second pad; and
an adjacent die interconnection circuit operably coupling the first pad of the
first functional die with the second pad of the at least a second
functional die, the first functional die and the second functional die
being jointly fabricated on a single semiconductor substrate, the
adjacent die interconnect extending electrical connection to the
contacts of the substrate.

- 32. The electronic system, as recited in claim 31, wherein the adjacent die interconnection circuit includes at least one conductor segment having a first end electrically coupled to the at least a first pad and a second end electrically coupled to the at least a second pad.
- 33. The electronic system, as recited in claim 32, wherein the adjacent die interconnection circuit further includes a conductive bump electrically coupled to the conductor segment configured for operatively coupling the conductor segment of the semiconductor device with the substrate contact.
- 34. The electronic system, as recited in claim 31, wherein the first functional die and the at least a second functional die are immediately adjacent on the semiconductor device.
- 35. The electronic system, as recited in claim 31, wherein the first functional die and the at least a second functional die are separated by at least one nonfunctional die on the semiconductor device.

- 36. The electronic system, as recited in claim 32, further comprising:
- at least one nonfunctional die including at least one pad, the nonfunctional die being formed on the common semiconductor substrate and located thereon between the first functional die and the at least a second function die; and
- wherein the at least one conductor segment extends between the at least a first pad and the at least one pad of the at least one nonfunctional die, the adjacent die interconnection circuit further including a second conductive segment extending between the at least one pad of the at least one nonfunctional die and the at least a second pad.
- 37. The electronic system, as recited in claim 36, further comprising a nonfunctional die pad isolation conductive segment including a first end electrically attached to the at the at least one conductor segment and the second conductive segment for coupling the at least a first pad of the first functional die with the at least a second pad of the at least a second functional die, the nonfunctional die pad isolation conductive segment further including a second end extending to the at least one nonfunctional die pad, the nonfunctional die pad isolation conductive segment being fabricated as an open circuit.
- 38. The electronic system, as recited in claim 36, wherein the at least one nonfunctional die further includes an isolation device coupled to the at least one pad of the at least one nonfunctional die for electrically isolating the at least one nonfunctional die from the adjacent die interconnection circuit.
- 39. A method of fabricating a semiconductor device, the method comprising: forming a plurality of dice on a common semiconductor substrate, each of the plurality of dice including at least one pad;
- identifying at least a first and second functional dice from among at least a portion of the plurality of dice;
- forming an adjacent die interconnection circuit between the at least one pad of the first functional die and the at least one pad of the second functional die; and

unitarily segmenting at least the first and second functional die from the common semiconductor wafer.

- 40. The method, as recited in claim 39, wherein forming an adjacent die interconnection comprises forming at least one conductor segment having a first end electrically coupled to the at least one pad of the first functional die and a second end electrically coupled to the at least one pad of the second functional die.
- 41. The method, as recited in claim 40, wherein forming an adjacent die interconnection further comprises forming a conductive bump electrically coupled to the conductor segment configured for operatively coupling the conductor segment of the semiconductor device with a substrate contact of a higher-level assembly.
- 42. The method, as recited in claim 39, wherein identifying comprises identifying the first and second functional dice as immediately adjacent ones from among the at least a portion of the plurality of dice on the common semiconductor wafer.
- 43. The method, as recited in claim 39, wherein identifying comprises identifying the first and second functional dice as separated by at least one nonfunctional dice from among the at least a portion of the plurality of dice on the common semiconductor wafer.
- 44. A method of functionally grouping a plurality of dice, comprising: fabricating a plurality of dice on a common semiconductor substrate, at least a portion of the plurality of dice each including at least one pad;
- identifying a plurality of functional and nonfunctional dice from among the at least a portion of the plurality of dice; and
- electrically coupling the pad of a first one of the plurality of functional dice with the pad of at least a second one of the plurality of functional dice for form a functional group of dice on the common semiconductor substrate.

- 45. The method, as recited in claim 44, further comprising testing the functional group as a single assembly.
- 46. The method, as recited in claim 44, further comprising unitarily segmenting the functional group from the common semiconductor wafer.